

S40M45F

Schottky Barrier

RECTIFIERS

40 AMPERES

45 VOLTS

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, Photovoltaic Solar cell protection, freewheeling and polarity protection diodes.

Features

- * Ultra Low Forward Voltage.
- *Low Switching noise.
- * High Current Capacity
- * Low Power Loss & High efficiency.
- *150°℃ Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives
- * ESD: 4KV(Min.) Human-Body Model

MAXIMUM RATINGS

Characteristic	Symbol	S40M45F	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
RMS Reverse Voltage	V _{R(RMS)}	32	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),	I _{F(AV)}	20 40	A
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	40	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	300	A
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL RESISTANCES

Typical Thermal Resistance junction to case

ELECTRICAL CHARACTERISTICS

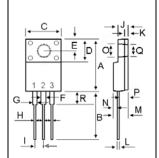
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 20 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 20 \text{ Amp } T_C = 125^{\circ}C$)	V _F		0.52 0.48	0.55 	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.07 30	0.15 	mA

R_{θjc}

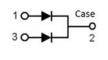
6.8

°C/w





DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	14.80	16.10		
В	12.65	13.80		
С	9.85	10.36		
D	4.60	6.80		
Е	2.50	3.50		
F	1.00	1.45		
G	1.00	1.45		
Н	0.30	0.90		
1	2.40	2.70		
J	2.34	3.30		
К	0.55	1.30		
L	0.36	0.80		
Μ	4.20	4.90		
Ν	1.10	1.80		
0	2.90	3.50		
Р	2.50	3.15		
Q	2.90	3.50		
R	3.10	4.85		





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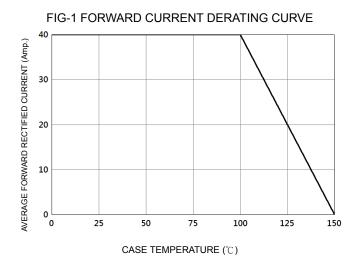
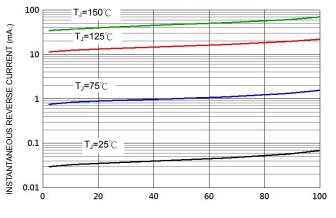


FIG-2 TYPICAL FORWARD CHARACTERISTICS

FORWARD VOLTAGE (V)

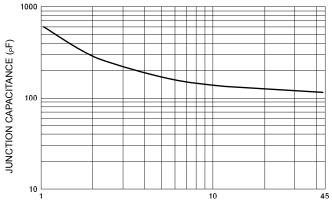
FIG-3 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

FIG-5 PEAK FORWARD SURGE CURRENT

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (V)



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